

### APPLICATIONS

- High Frequency Applications
- High Power Choppers And Inverters
- Welding
- Ultrasonic Generators
- Induction Heating
- 400Hz UPS
- PWM Inverters

### FEATURES

- Low Loss Asymmetrical Diffusion Structure
- High Interdigitated Amplifying Gate
- Gate Assisted Turn-off With Exclusive Bypass Diode
- Fully Characterised For Operation up to 40kHz
- Directly Compatible With 220-480 A.c. Mains

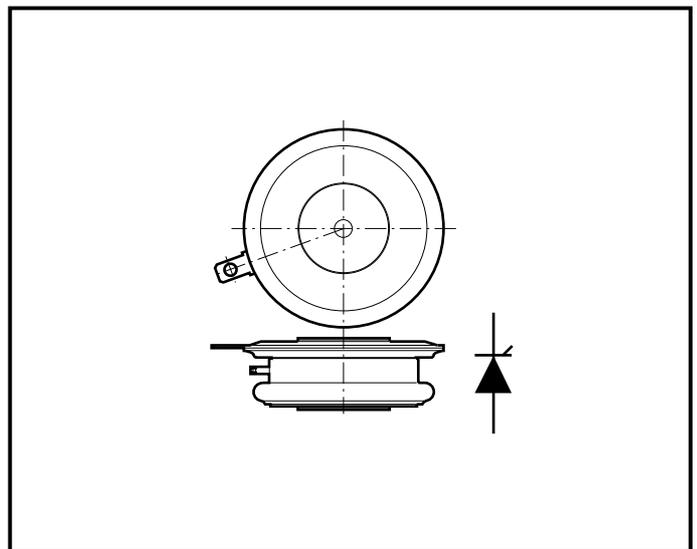
### VOLTAGE RATINGS

Type Number	Repetitive Peak Off-state Voltage $V_{DRM}$ V	Repetitive Peak Reverse Voltage $V_{RRM}$ V
TA329 14 Q	1400	10
TA329 12 Q	1200	10
TA329 10 Q	1000	10

Lower voltage grades available.

### KEY PARAMETERS

$V_{DRM}$	<b>1400V</b>
$I_{T(RMS)}$	<b>370A</b>
$I_{TSM}$	<b>2000A</b>
$dV/dt$	<b>1000V/μs</b>
$dI/dt$	<b>1000A/μs</b>
$t_q$	<b>7.0μs</b>



Outline type code: MU86.  
See Package Details for further information.

## CURRENT AND SURGE RATINGS

Symbol	Parameter	Conditions	Max.	Units
<b>Double Side Cooled</b>				
$I_{T(RMS)}$	RMS value	Half sine wave, duty cycle 50%, $T_{case} = 80^{\circ}C$ , $T_j = 125^{\circ}C$ .	370	A
$I_{TSM}$	Surge (non-repetitive) on-state current	$T_j = 125^{\circ}C$ , $t_p = 1ms$ , $V_R = 0$	2000	A
$I^2t$	$I^2t$ for fusing	$t_p \geq 10ms$	$20 \times 10^3$	$A^2s$

## THERMAL AND MECHANICAL DATA

Symbol	Parameter	Conditions		Min.	Max.	Units
$R_{th(j-c)}$	Thermal resistance - junction to case	Double side cooled	dc	-	0.085	$^{\circ}C/W$
		Single side cooled	Anode dc	-	0.153	$^{\circ}C/W$
			Cathode dc	-	0.204	$^{\circ}C/W$
$R_{th(c-h)}$	Thermal resistance - case to heatsink	Clamping force 4.0kN with mounting compound	Double side	-	0.02	$^{\circ}C/W$
			Single side	-	0.04	$^{\circ}C/W$
$T_{vj}$	Virtual junction temperature	On-state (conducting)		-	135	$^{\circ}C$
		Reverse (blocking)		-	125	$^{\circ}C$
$T_{stg}$	Storage temperature range			-40	150	$^{\circ}C$
-	Clamping force			3.6	4.4	kN

**DYNAMIC CHARACTERISTICS**

Symbol	Parameter	Conditions	Min.	Max.	Units	
$V_{TM}$	Maximum on-state voltage	At 600A peak, $T_{case} = 125^{\circ}C$	-	2.5	V	
$I_{RRM}$	Peak reverse current	At $V_{RRM}$ , $T_{case} = 125^{\circ}C$	-	30	mA	
$I_{DRM}$	Off-state current	At $V_{DRM}$ , $T_{case} = 125^{\circ}C$	-	1	mA	
dV/dt	Maximum linear rate of rise of off-state voltage	To 60% $V_{DRM}$ , $T_j = 125^{\circ}C$ , Gate open circuit	-	1000	V/ $\mu$ s	
dI/dt	Rate of rise of on-state current	Gate source 20V, 20 $\Omega$ $t_i \leq 5\mu$ s.	Non-repetitive	-	1000	A/ $\mu$ s
			Repetitive	-	500	A/ $\mu$ s
$t_q^{\dagger}$	Max. gate assisted turn-off time (with feedback diode)	$T_j = 125^{\circ}C$ , $I_{T(PK)} = 200A$ , $t_p = 25\mu$ s (half sine wave), $V_R = DF451$ Diode voltage drop, dV/dt = 600V/ $\mu$ s (linear to 60% $V_{DRM}$ ), $V_{GK} = -5V$	-	7	$\mu$ s	
$t_q$	Max. turn-off time (with feedback diode)	$T_j = 125^{\circ}C$ , $I_{TM} = 100A$ , $t_p > 100\mu$ s, $dI_R/dt = 30A/\mu$ s, $V_R = 1V$ , dV/dt = 600V/ $\mu$ s (linear to 60% $V_{DRM}$ ), Gate open.	-	10	$\mu$ s	

**GATE TRIGGER CHARACTERISTICS AND RATINGS**

Symbol	Parameter	Conditions	Typ.	Max.	Units
$V_{GT}$	Gate trigger voltage	$V_{DWM} = 12V$ , $R_L = 3\Omega$ , $T_{case} = 25^{\circ}C$	-	4	V
$I_{GT}$	Gate trigger current	$V_{DWM} = 12V$ , $R_L = 3\Omega$ , $T_{case} = 25^{\circ}C$	-	250	mA
$V_{RGM}$	Peak reverse gate voltage	-	-	7	V
$I_{FGM}$	Peak forward gate current	-	-	10	A
$P_{GM}$	Peak gate power	-	-	50	W
$P_{G(AV)}$	Average gate power	-	-	15	W

CURVES

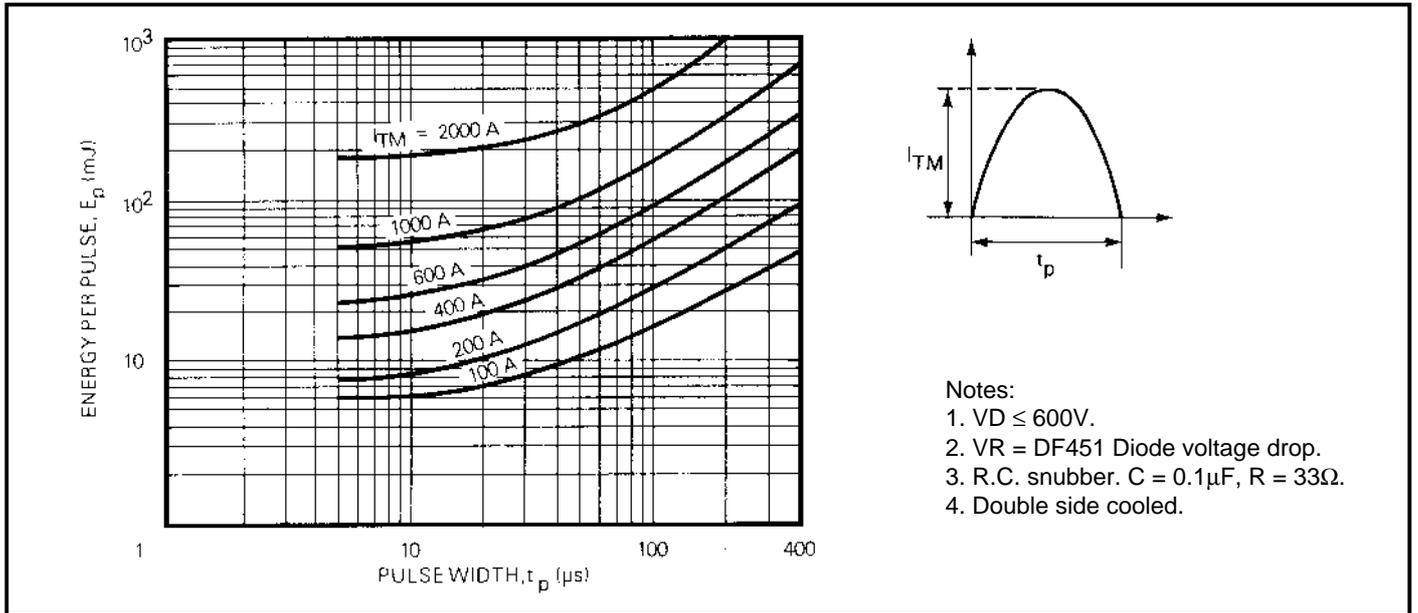


Fig.1 Energy per pulse for sinusoidal pulses.

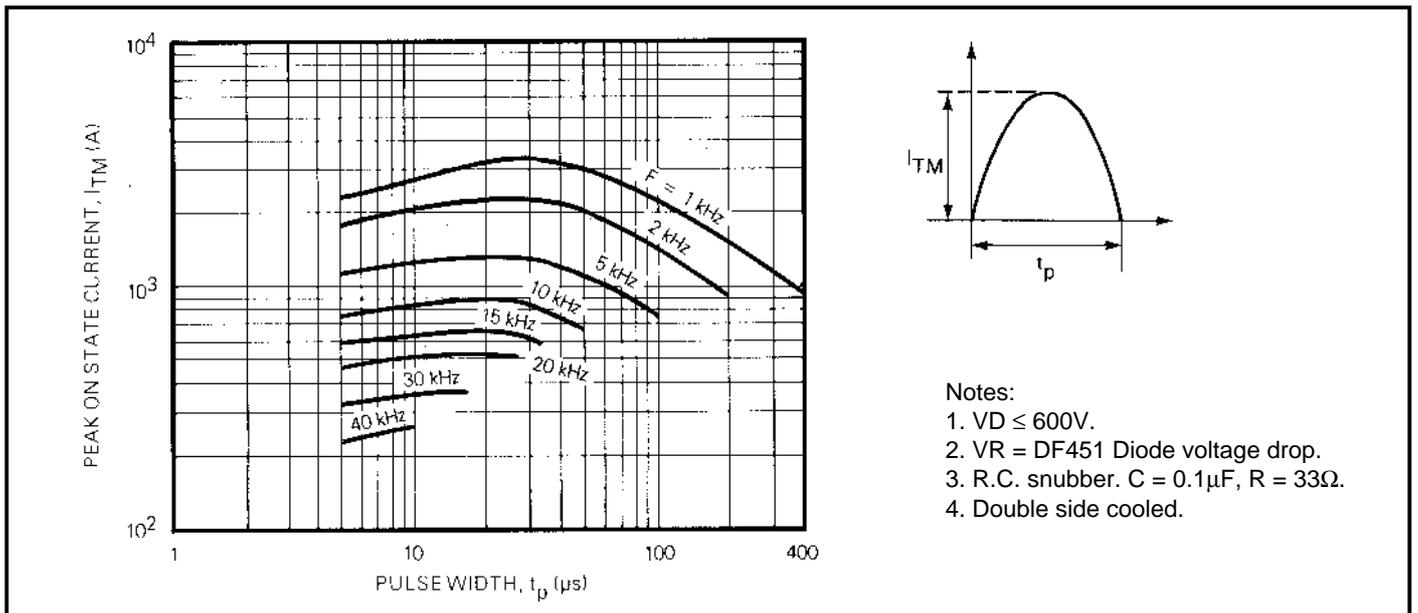
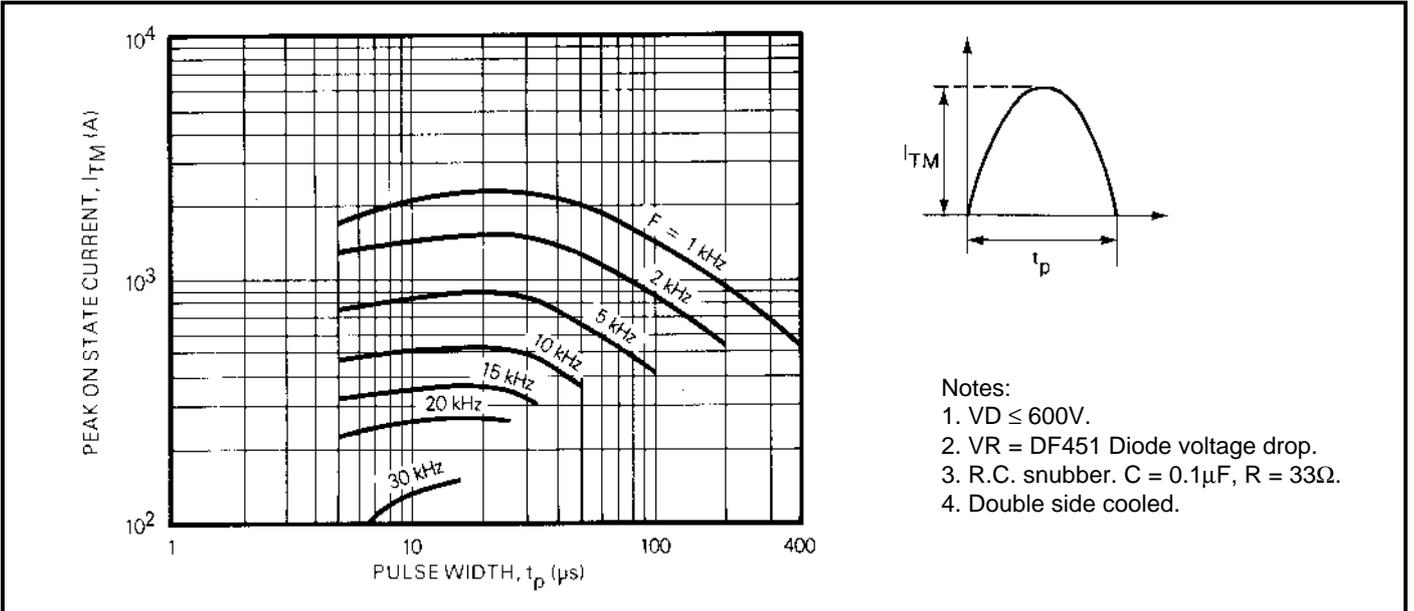
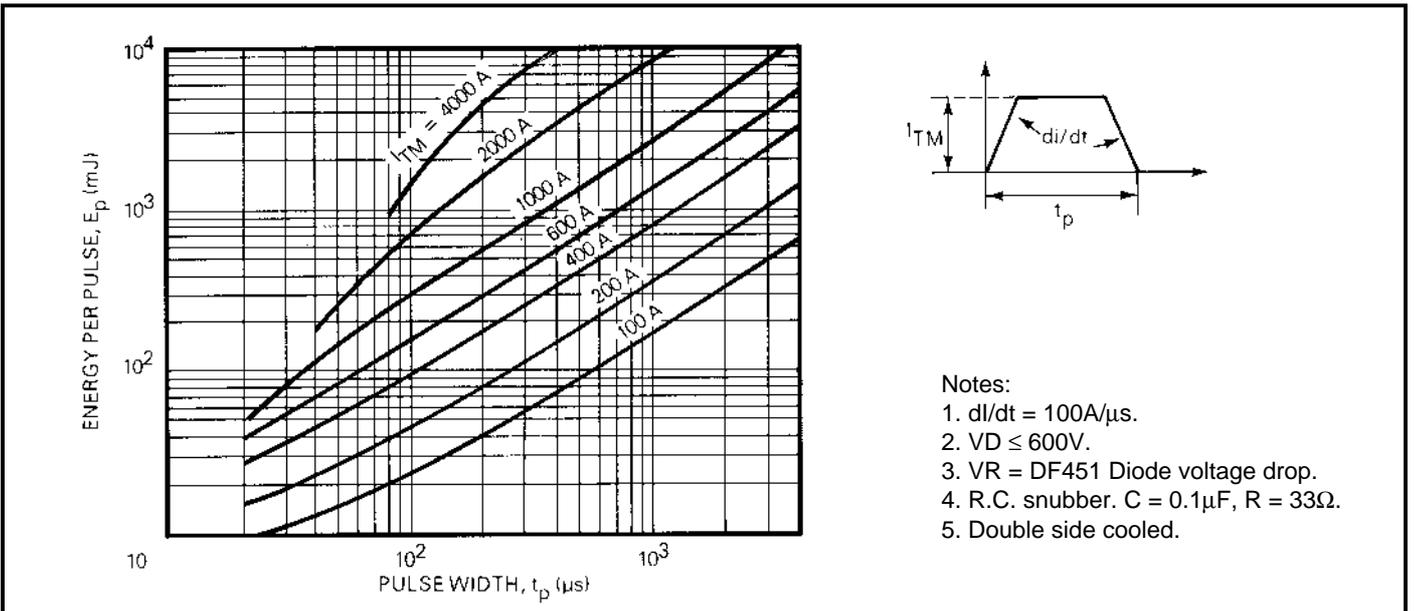


Fig.2 Maximum allowable peak on-state current vs pulse width for  $T_{case} = 65^\circ$ C.



**Fig.3 Maximum allowable peak on-state current vs pulse width for  $T_{case} = 90^\circ C$ .**



**Fig.4 Energy per pulse for trapezoidal pulses**

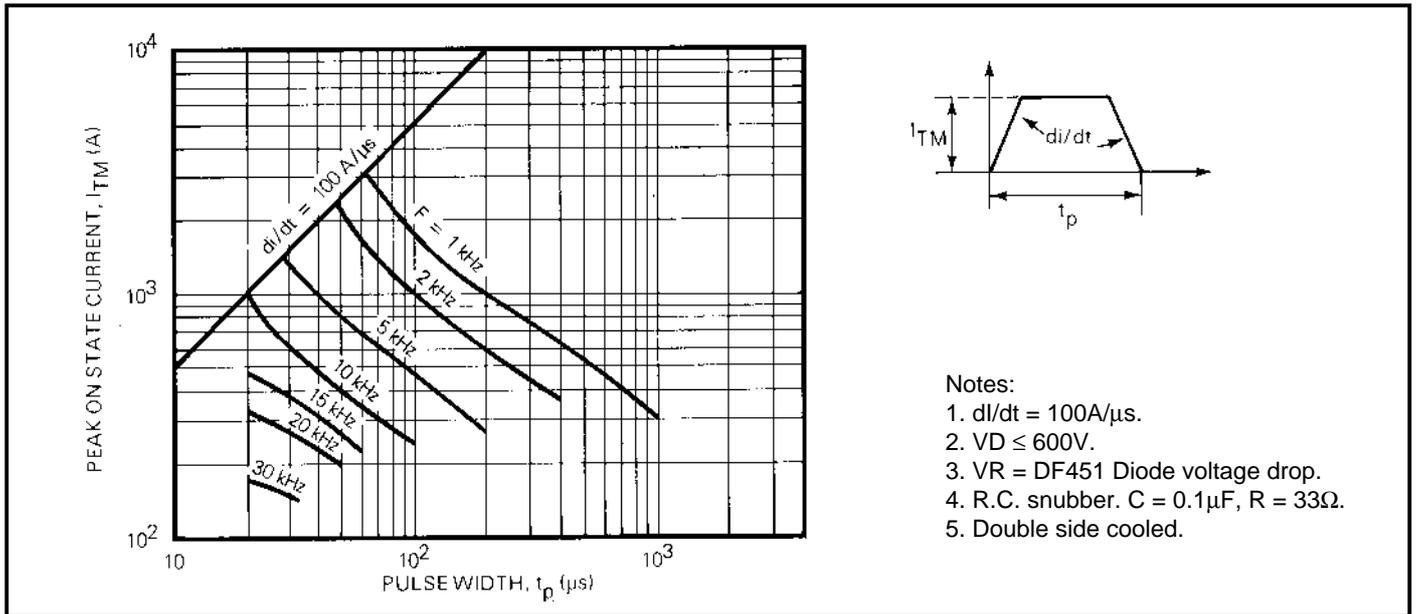


Fig.5 Maximum allowable peak on-state current vs pulse width for  $T_{case} = 65^\circ C$ .

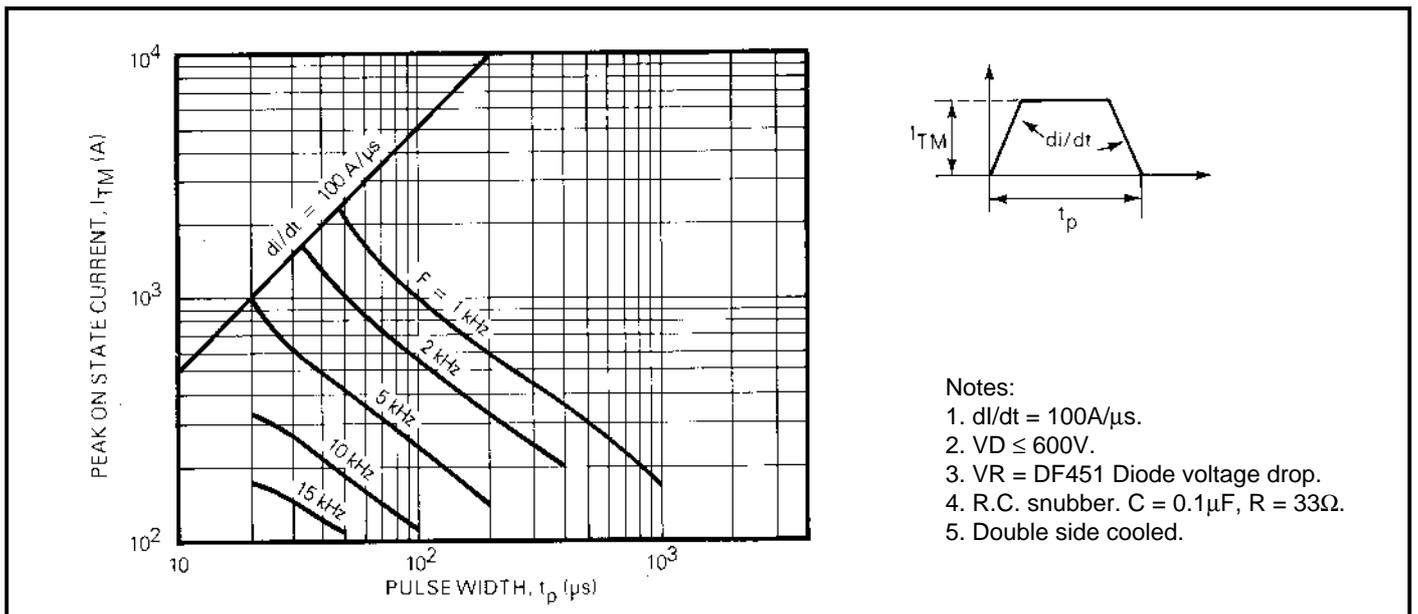
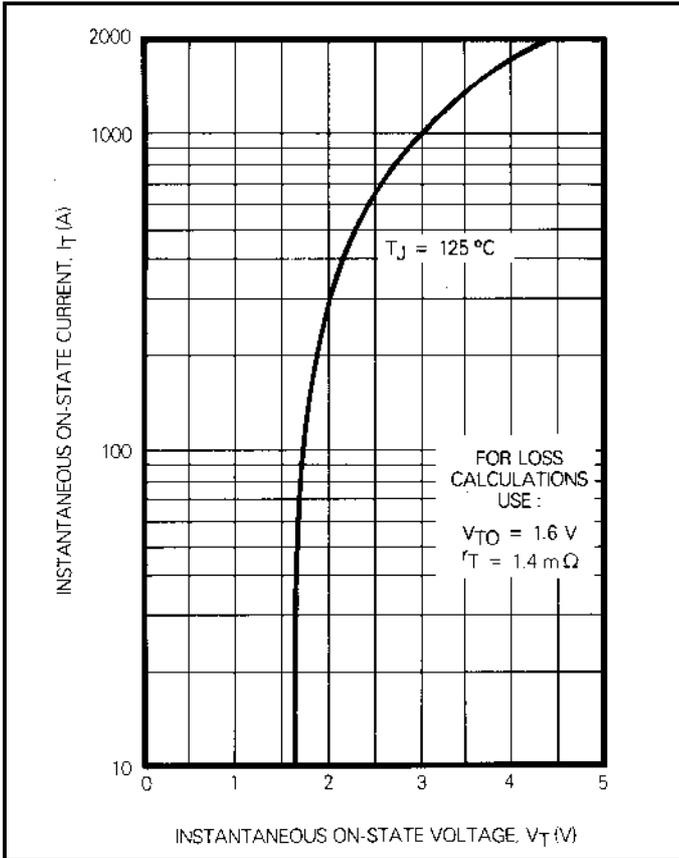
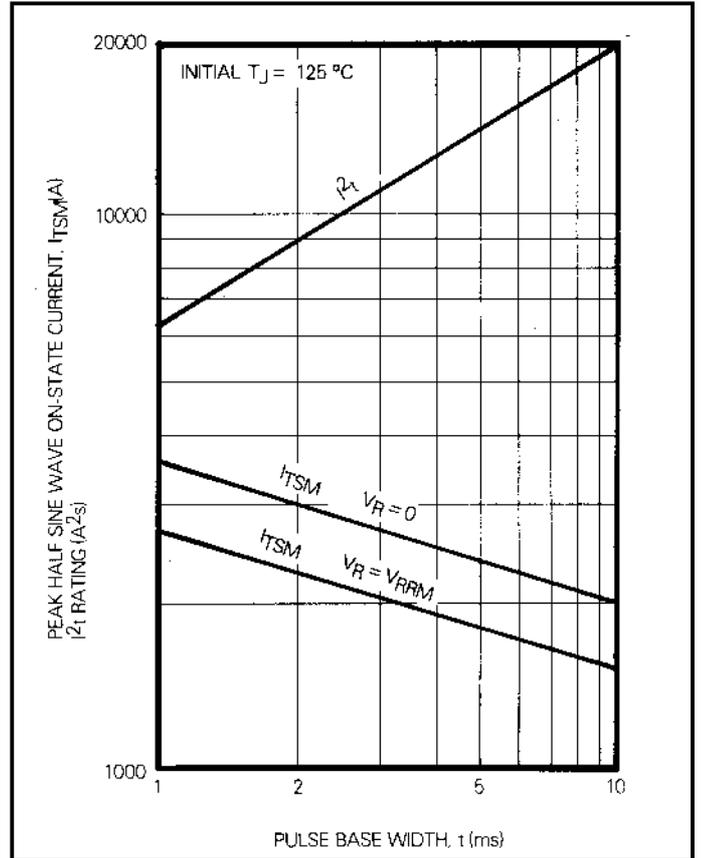


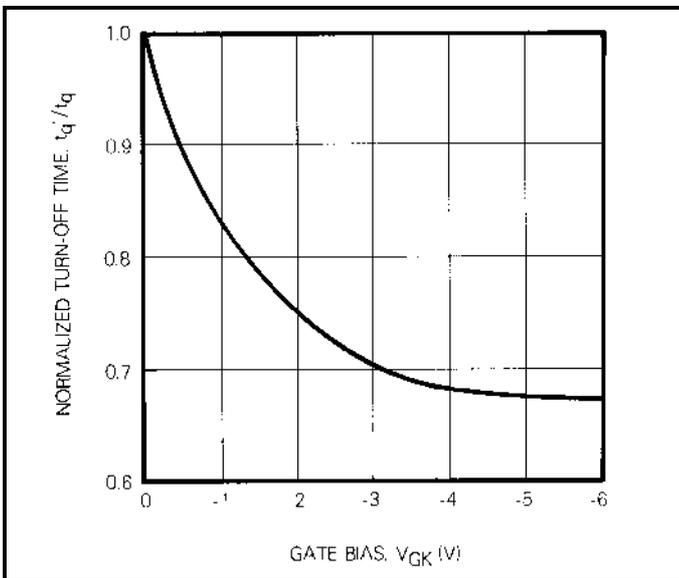
Fig.6 Maximum allowable peak on-state current vs pulse width for  $T_{case} = 90^\circ C$ .



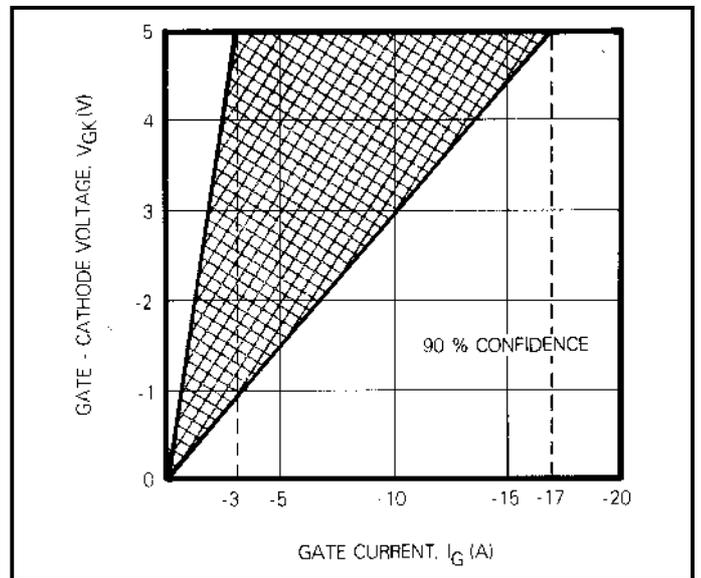
**Fig.9 Maximum on-state conduction characteristic**



**Fig.8 Non-repetitive sub-cycle surge on-state current and  $I^2t$  rating.**



**Fig.9 Typical variation of effective turn-off time ( $t_q^\dagger$ ) with negative gate bias.**



**Fig.10 Reverse gate characteristics**

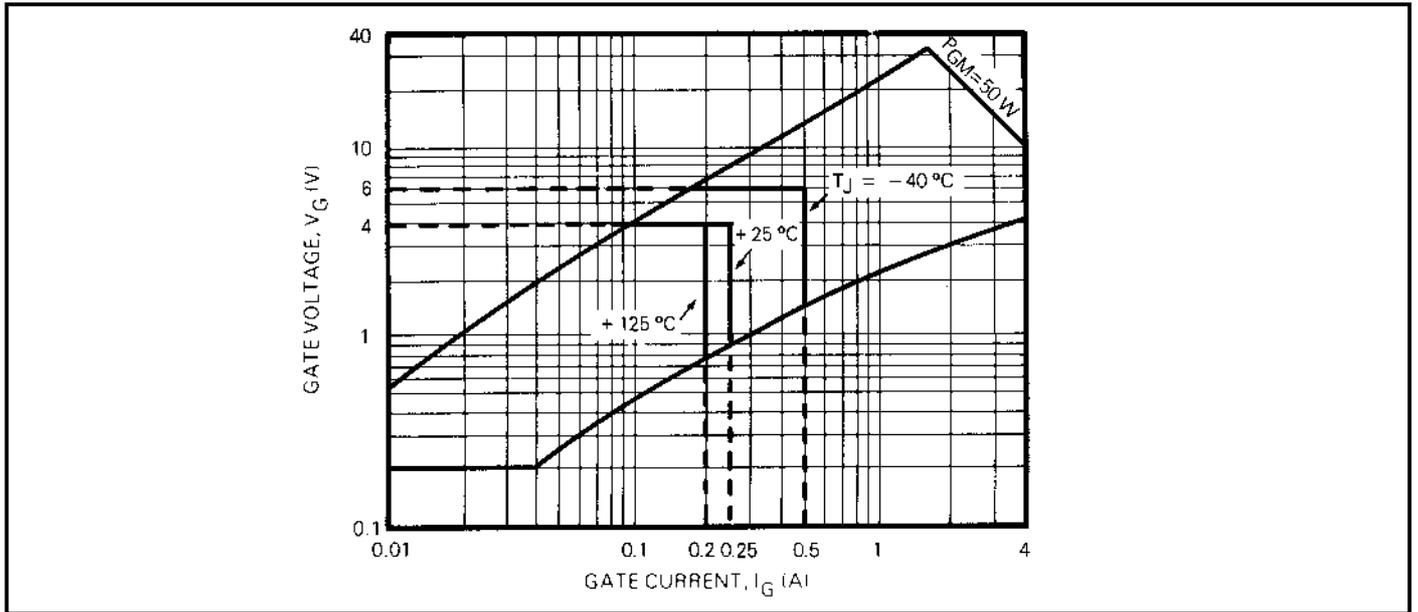


Fig.11 Gate trigger characteristics

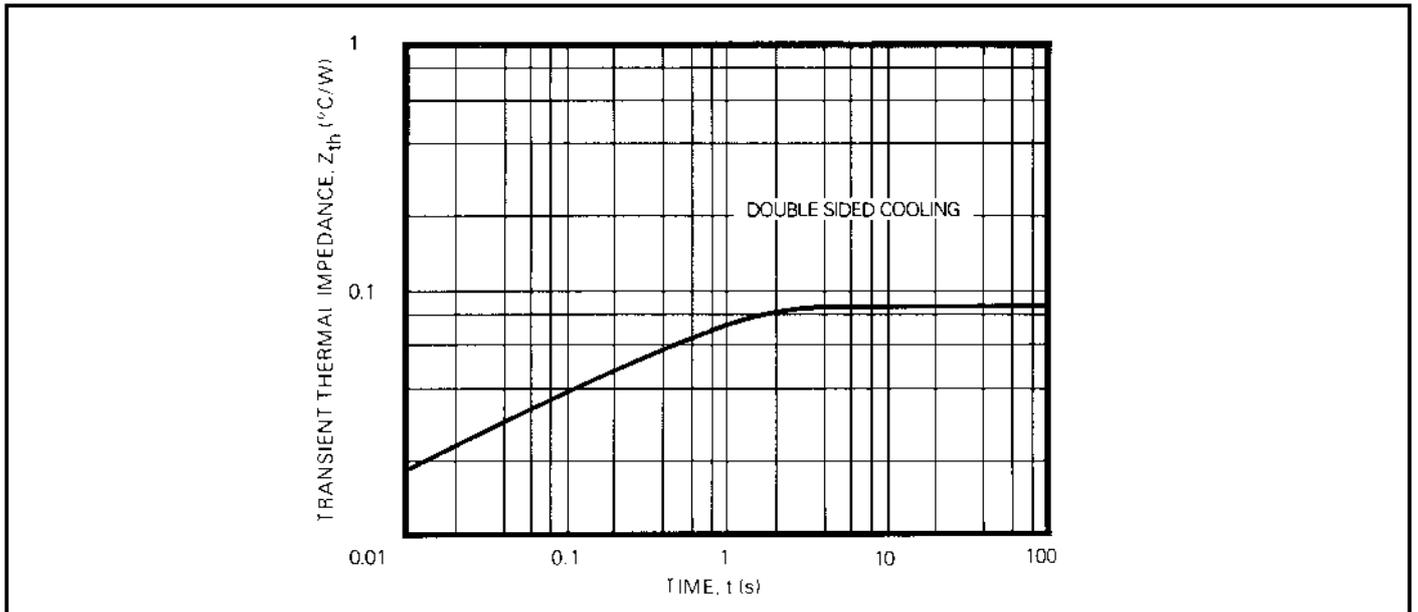
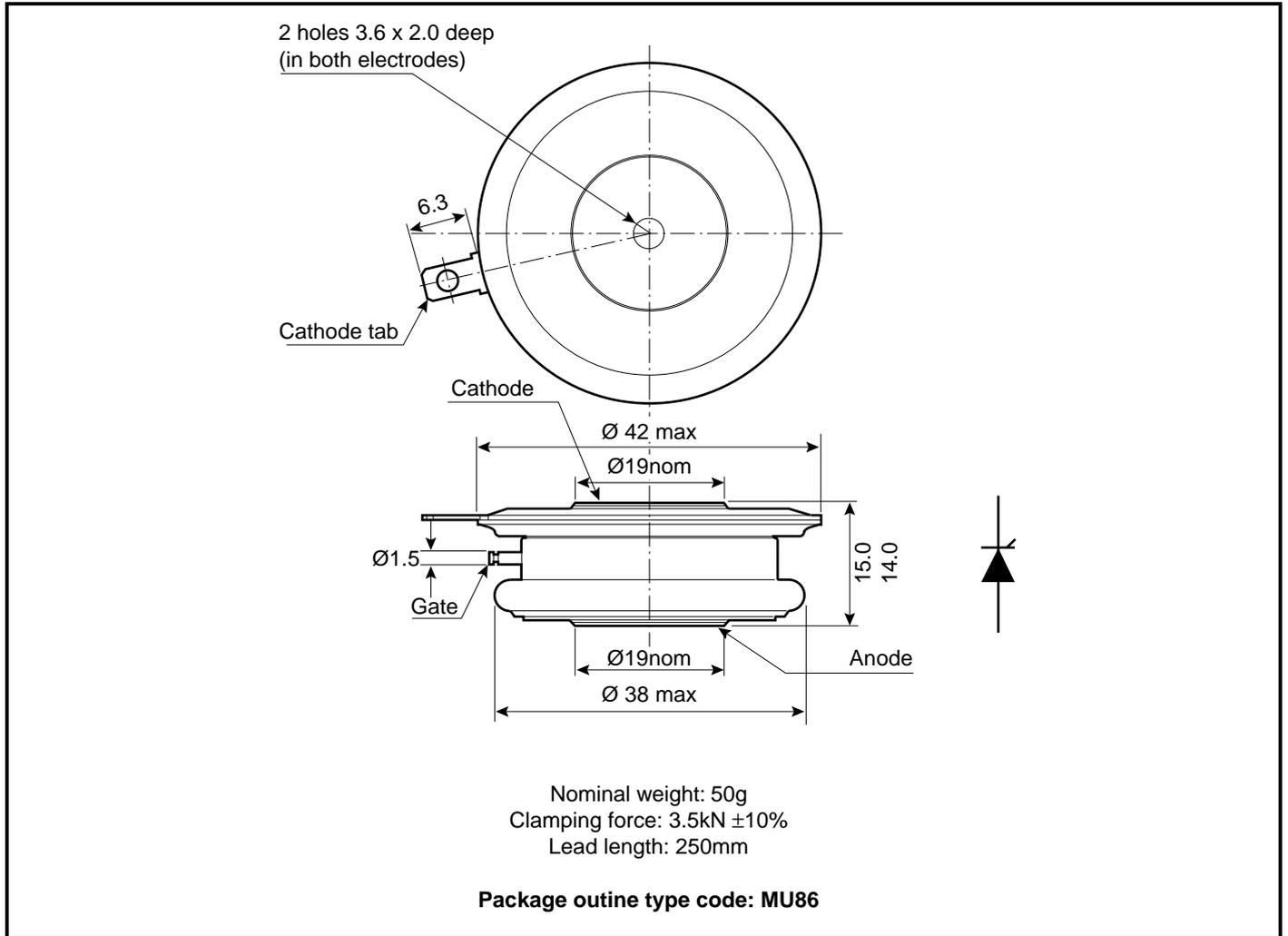


Fig.12 Transient thermal impedance - junction to case

**PACKAGE DETAILS**

For further package information, please contact Customer Services. All dimensions in mm, unless stated otherwise.  
DO NOT SCALE.



## POWER ASSEMBLY CAPABILITY

The Power Assembly group was set up to provide a support service for those customers requiring more than the basic semiconductor, and has developed a flexible range of heatsink and clamping systems in line with advances in device voltages and current capability of our semiconductors.

We offer an extensive range of air and liquid cooled assemblies covering the full range of circuit designs in general use today. The Assembly group continues to offer high quality engineering support dedicated to designing new units to satisfy the growing needs of our customers.

Using the latest CAD methods our team of design and applications engineers aim to provide the Power Assembly Complete Solution (PACs).

## DEVICE CLAMPS

Disc devices require the correct clamping force to ensure their safe operation. The PACS range includes a varied selection of pre-loaded clamps to suit all of our manufactured devices. Types available include cube clamps for single side cooling of 'T' 23mm and 'E' 30mm discs, and bar clamps right up to 83kN for our 'Z' 100mm thyristors and diodes.

Clamps are available for single or double side cooling, with high insulation versions for high voltage assemblies.

Please refer to our application note on device clamping, AN4839

## HEATSINKS

The Power Assembly group has its own proprietary range of extruded aluminium heatsinks. They have been designed to optimise the performance of Dynex semiconductors. Data with respect to air natural, forced air and liquid cooling (with flow rates) is available on request.

For further information on device clamps, heatsinks and assemblies, please contact your nearest sales representative or customer service office.



<http://www.dynexsemi.com>

**e-mail: [power\\_solutions@dynexsemi.com](mailto:power_solutions@dynexsemi.com)**

**HEADQUARTERS OPERATIONS**  
**DYNEX SEMICONDUCTOR LTD**  
 Doddington Road, Lincoln.  
 Lincolnshire. LN6 3LF. United Kingdom.  
 Tel: 00-44-(0)1522-500500  
 Fax: 00-44-(0)1522-500550

**CUSTOMER SERVICE**  
 Tel: +44 (0)1522 502753 / 502901. Fax: +44 (0)1522 500020

### SALES OFFICES

**Benelux, Italy & Switzerland:** Tel: +33 (0)1 64 66 42 17. Fax: +33 (0)1 64 66 42 19.

**France & Spain:** Tel: +33 (0)2 47 55 75 52. Fax: +33 (0)2 47 55 75 59.

**Germany, Northern Europe & Rest Of World:** Tel: +44 (0)1522 502753 / 502901. Fax: +44 (0)1522 500020

**North America:** Toll Free: 1.888.33.DYNEX (39639) / Tel: (949) 733-3005. Fax: (949) 733-2986.

These offices are supported by Representatives and Distributors in many countries world-wide.

© Dynex Semiconductor 2002 Publication No. DS4680-3 Issue No. 3.1 July 2002

TECHNICAL DOCUMENTATION – NOT FOR RESALE. PRODUCED IN UNITED KINGDOM

### Datasheet Annotations:

Dynex Semiconductor annotate datasheets in the top right hand corner of the front page, to indicate product status. The annotations are as follows:-

**Target Information:** This is the most tentative form of information and represents a very preliminary specification. No actual design work on the product has been started.

**Preliminary Information:** The product is in design and development. The datasheet represents the product as it is understood but details may change.

**Advance Information:** The product design is complete and final characterisation for volume production is well in hand.

This publication is issued to provide information only which (unless agreed by the Company in writing) may not be used, applied or reproduced for any purpose nor form part of any order or contract nor to be regarded as a representation relating to the products or services concerned. No warranty or guarantee express or implied is made regarding the capability, performance or suitability of any product or service. The Company reserves the right to alter without prior notice the specification, design or price of any product or service. Information concerning possible methods of use is provided as a guide only and does not constitute any guarantee that such methods of use will be satisfactory in a specific piece of equipment. It is the user's responsibility to fully determine the performance and suitability of any equipment using such information and to ensure that any publication or data used is up to date and has not been superseded. These products are not suitable for use in any medical products whose failure to perform may result in significant injury or death to the user. All products and materials are sold and services provided subject to the Company's conditions of sale, which are available on request.

All brand names and product names used in this publication are trademarks, registered trademarks or trade names of their respective owners.

## POWER ASSEMBLY CAPABILITY

The Power Assembly group was set up to provide a support service for those customers requiring more than the basic semiconductor, and has developed a flexible range of heatsink and clamping systems in line with advances in device voltages and current capability of our semiconductors.

We offer an extensive range of air and liquid cooled assemblies covering the full range of circuit designs in general use today. The Assembly group offers high quality engineering support dedicated to designing new units to satisfy the growing needs of our customers.

Using the latest CAD methods our team of design and applications engineers aim to provide the Power Assembly Complete Solution (PACs).

## HEATSINKS

The Power Assembly group has its own proprietary range of extruded aluminium heatsinks which have been designed to optimise the performance of Dynex semiconductors. Data with respect to air natural, forced air and liquid cooling (with flow rates) is available on request.

For further information on device clamps, heatsinks and assemblies, please contact your nearest sales representative or Customer Services.



<http://www.dynexsemi.com>

**e-mail: [power\\_solutions@dynexsemi.com](mailto:power_solutions@dynexsemi.com)**

HEADQUARTERS OPERATIONS  
**DYNEX SEMICONDUCTOR LTD**  
Doddington Road, Lincoln.  
Lincolnshire. LN6 3LF. United Kingdom.  
Tel: +44-(0)1522-500500  
Fax: +44-(0)1522-500550

CUSTOMER SERVICE  
Tel: +44 (0)1522 502753 / 502901. Fax: +44 (0)1522 500020

SALES OFFICES  
**Benelux, Italy & Switzerland:** Tel: +33 (0)1 64 66 42 17. Fax: +33 (0)1 64 66 42 19.  
**France:** Tel: +33 (0)2 47 55 75 52. Fax: +33 (0)2 47 55 75 59.  
**Germany, Northern Europe, Spain & Rest Of World:** Tel: +44 (0)1522 502753 / 502901.  
Fax: +44 (0)1522 500020  
**North America:** Tel: (613) 723-7035. Fax: (613) 723-1518. Toll Free: 1.888.33.DYNEX (39639) /  
Tel: (949) 733-3005. Fax: (949) 733-2986.

These offices are supported by Representatives and Distributors in many countries world-wide.  
© Dynex Semiconductor 2002 TECHNICAL DOCUMENTATION – NOT FOR RESALE. PRODUCED IN UNITED KINGDOM

### Datasheet Annotations:

Dynex Semiconductor annotate datasheets in the top right hand corner of the front page, to indicate product status. The annotations are as follows:-

**Target Information:** This is the most tentative form of information and represents a very preliminary specification. No actual design work on the product has been started.

**Preliminary Information:** The product is in design and development. The datasheet represents the product as it is understood but details may change.

**Advance Information:** The product design is complete and final characterisation for volume production is well in hand.

**No Annotation:** The product parameters are fixed and the product is available to datasheet specification.

This publication is issued to provide information only which (unless agreed by the Company in writing) may not be used, applied or reproduced for any purpose nor form part of any order or contract nor to be regarded as a representation relating to the products or services concerned. No warranty or guarantee express or implied is made regarding the capability, performance or suitability of any product or service. The Company reserves the right to alter without prior notice the specification, design or price of any product or service. Information concerning possible methods of use is provided as a guide only and does not constitute any guarantee that such methods of use will be satisfactory in a specific piece of equipment. It is the user's responsibility to fully determine the performance and suitability of any equipment using such information and to ensure that any publication or data used is up to date and has not been superseded. These products are not suitable for use in any medical products whose failure to perform may result in significant injury or death to the user. All products and materials are sold and services provided subject to the Company's conditions of sale, which are available on request.

All brand names and product names used in this publication are trademarks, registered trademarks or trade names of their respective owners.